

## Low Voltage, 0.4 $\Omega$ , Dual SPDT Analog Switch

#### **DESCRIPTION**

The DG2731/2732/2733 are low voltage, low on-resistance, dual single-pole/double-throw (SPDT) monolithic CMOS analog switches designed for high performance switching of analog signals. Combining low-power, high speed, low on-resistance, and small package size, the DG2731/2732/2733 are ideal for portable and battery power applications.

The DG2731/2732/2733 have an operation range from 1.6 V to 4.3 V single supply. The DG2731 and DG2732 have two separate control pins with reverse control logic. The DG2733 has an EN pin to enable the device when the logic is high.

The DG2731/2732/2733 are 1.6-V logic compatible, allowing the easy interface with low voltage DSP or MCU control logic and ideal for one cell Li-ion battery direct power.

The switch conducts signals within power rails equally well in both directions when on, and blocks up to the power supply level when off. Break-before-make is guaranteed.

The DG2731/2732/2733 are built on Vishay Siliconix's sub micron CMOS low voltage process technology and provides greater than 300 mA latch-up protection, as tested per JESD78.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2731/2732/2733 are offered in a DFN or MSOP package. The DFN package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-E4" suffix. The MSOP package uses 100% matte Tin device termination and is represented by the lead (Pb)-free "-E3" suffix. Both the matte Tin and nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL ratings.

#### **FEATURES**

- Low Voltage Operation (1.65 V to 4.3 V)
- Low On-Resistance r<sub>ON</sub>: 0.3 Ω@ 3.6 V
- Fast Switching: T<sub>ON</sub> = 50 ns @ 4.3 V
- T<sub>OFF</sub> = 14 ns @ 4.3 V
- Latch-Up Current > 300 mA (JESD78)



ROHS

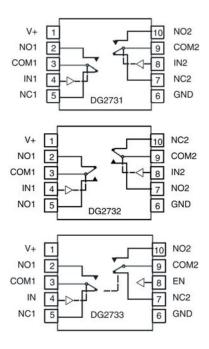
#### **BENEFITS**

- Reduced Power Consumption
- High Accuracy
- Reduce Board Space
- TTL/1.6-V Logic Compatible

#### **APPLICATIONS**

- Cellular Phones
- Speaker Headset Switching
- · Audio and Video Signal Routing
- PCMCIA Cards
- · Battery Operated Systems

## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





TRUTH TABLE						
Logic	EN (DG2733 only)	EN (DG2733 only) NC1, 2 NO1, 2				
0	1	ON	OFF			
1	1	OFF	ON			
0	0	OFF	OFF			
1	0	OFF	OFF			

ORDERING INFORMATION					
Temp Range	Package	Part Number			
-40 to 85°C	MSOP-10	DG2731DQ-T1-E3 DG2732DQ-T1-E3 DG2733DQ-T1-E3			
	DFN-10	DG2731DN-T1-E4 DG2732DN-T1-E4 DG2733DN-T1-E4			

<b>ABSOLUTE MAXIMUM RATINGS</b> T <sub>A</sub> = 25 °C, unless otherwise noted						
Parameter	Symbol	Limit	Unit			
Reference to GND	V+		-0.3 to 5.0	V		
neierence to GND	IN, COM, NC, NO <sup>a</sup>		$-0.3$ to $(V^+ + 0.3)$			
Current (Any terminal except NO, NC or	COM)		30			
Continuous Current (NO, NC, or COM)		±250	mA			
Peak Current (Pulsed at 1 ms, 10 % dut	y cycle)		±500			
Storage Temperature (D Suffix)		-65 to 150	°C			
D 1	10-PIN MSOP					
Package Solder Reflow Conditions <sup>d</sup>	10-PIN DFN					
Davis Dissipation (Dasharas)	MSOP-10 <sup>c</sup>		320	mW		
Power Dissipation (Packages) <sup>b</sup>	DFN-10 <sup>d</sup>		1191	11100		

#### Notes

- a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC Board.
- c. Derate 4.0 mW/C above 70°C
- d. Derate 14.9 mW/C above 70°C
- e. Manual soldering with iron is not recommended for leadless components. The QFN is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

<b>SPECIFICATIONS</b>	(V+ = 1.8 \	V)					
	Symbol	Test Condition Otherwise Unless Specified V+ = 1.8 V, V <sub>IN</sub> = 0.4 or 1.4 V <sup>e</sup>	Temp <sup>a</sup>	Limits -40 to 85°C			
Parameter				Min <sup>b</sup>	Typ <sup>c</sup>	Max <sup>b</sup>	Unit
Analog Switch							
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC}, V_{COM}$		Full	0		V+	٧
On-Resistance	r <sub>ON</sub>	$V+ = 1.8 \text{ V}, V_{COM} = 0.9 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room		0.7	1.0	Ω
On-nesistance			Full			1.2	
Digital Control	•						
Input High Voltage	V <sub>INH</sub>		Full	1.4			V
Input Low Voltage	V <sub>INL</sub>		Full			0.4	V
Input Capacitance	C <sub>in</sub>		Full		4		pF
Power Supply	•		•		•	•	•
Power Supply Current	I+	V <sub>IN</sub> = 0 or V+	Full			1.0	μA



SPECIFICATIONS (	V + = 3 V							
		Test Condition Otherwise Unless Specified		<b>Limits</b> -40 to 85°C				
Parameter	Symbol	$V+ = 3 V, \pm 10 \%, V_{IN} = 0.5 \text{ or } 1.4 \text{ V}^e$	Temp <sup>a</sup>	Min <sup>b</sup>	Typ <sup>c</sup>	Max <sup>b</sup>	Unit	
Analog Switch	-							
Analog Signal Range <sup>d</sup>	$V_{NO}, V_{NC}, V_{COM}$		Full	0		V+	V	
		V+ = 2.7 V, V <sub>COM</sub> = 0.5 V, I <sub>NO</sub> , I <sub>NC</sub> = 100 mA	D		0.35	0.45		
On-Resistance	r <sub>ON</sub>	$V+ = 2.7 \text{ V}, V_{COM} = 1.5 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room		0.3	0.45		
			Full			0.6	Ω	
r <sub>ON</sub> Match <sup>d</sup>	$\Delta r_{ON}$	$V+ = 2.7 \text{ V}, V_{COM} = 0.5 \text{ to } 1.5 \text{ V},$ $I_{NO}, I_{NC} = 100 \text{ mA}$	Room		0.03	0.06		
Switch Off Leakage Current	I <sub>NO(off)</sub> , I <sub>NC(offF)</sub>		Room Full	−1 −10		1 10		
Switch Oil Leakage Current	I <sub>COM(off)</sub>	$V_{COM} = 3.0 \text{ V} / 0.3 \text{ V}$	Room Full	−1 −10		1 10	nA	
Channel-On Leakage Current	I <sub>COM(on)</sub>	$V+ = 3.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 3.0 \text{ V} / 0.3 \text{ V}$	Room Full	−1 −10		1 10		
Digital Control			, ,			,		
Input High Voltage	V <sub>INH</sub>		Full	1.4			V	
Input Low Voltage	$V_{INL}$		Full			0.5	•	
Input Capacitance	C <sub>in</sub>		Full		5		pF	
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	$V_{IN} = 0 \text{ or } V+$	Full	-1		1	μΑ	
Dynamic Characteristics			, ,			,		
Turn-On Time	t <sub>ON</sub>	V+ = 3.6 V	Room Full		85	110 140		
Turn-Off Time	t <sub>OFF</sub>	$V_{NO}$ or $V_{NC} = 1.5 \text{ V}$ , $R_L = 50 \Omega$ , $C_L = 35 \text{ pF}$	Room Full		17	30 35	ns	
Break-Before-Make Time	t <sub>BBM</sub>		Full	10				
Charge Injection <sup>d</sup>	Q <sub>INJ</sub>	$C_L$ = 1 nF, $V_{GEN}$ = 0 V, $R_{GEN}$ = 0 $\Omega$	Room		9		рС	
Off-Isolation <sup>d</sup>	O <sub>IRR</sub>	$R_1 = 50 \Omega$ , $C_1 = 5 pF$ , $f = 100 kHz$	Room		-75		<b>پا</b> ك	
Crosstalk <sup>d</sup>	X <sub>TALK</sub>	17L = 50 24, OL = 5 pr, I = 100 km2	Room		-75		dB	
h :: 0,00 ii d	C <sub>NO(off)</sub>		Room		104			
N <sub>O</sub> , N <sub>C</sub> Off Capacitance <sup>d</sup>	C <sub>NC(off)</sub>	V = 0 or V: 1 1 MH=	Room		104			
0, 10 0 ;; 4	C <sub>NO(on)</sub>	$V_{IN} = 0$ or $V_{+}$ , $f = 1$ MHz	Room		230		pF	
Channel On Capacitance <sup>d</sup>	C <sub>NC(on)</sub>		Room		230		1	
Power Supply								
Power Supply Range	V+			2.7		3.3	V	
Power Supply Current	I+	$V_{IN} = 0 \text{ or } V+$	Full			1.0	μΑ	
Turn-On Time DG2733 (EN)	t <sub>ON(EN)</sub>	V+ = 3.6 V	Room Full		79	105 135	ns	
Turn-Off Time DG2733 (EN)	t <sub>OFF(EN)</sub>	$V_{NO}$ or $V_{NC}$ = 1.5 V, $R_L$ = 50 $\Omega$ , $C_L$ = 35 pF			17	29 35	115	

### DG2731/2732/2733

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SPECIFICATIONS	(V+ = 4.3 \	V)					
		Test Condition Otherwise Unless Specified		Limits -40 to 85°C			
Parameter	Symbol	$V+ = 4.3 \text{ V}, V_{IN} = 0.5 \text{ or } 1.6 \text{ V}^{e}$	Temp <sup>a</sup>	Min <sup>b</sup>	Typ <sup>c</sup>	Max <sup>b</sup>	Unit
Analog Switch	-					•	
Analog Signal Range <sup>d</sup>	V <sub>NO</sub> , V <sub>NC</sub> , V <sub>COM</sub>		Full	0		V+	V
		$V+ = 4.3 \text{ V}, V_{COM} = 0.9 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Deam		0.29	0.4	
On-Resistance	r <sub>ON</sub>	$V+ = 4.3 \text{ V}, V_{COM} = 2.5 \text{ V}, I_{NO}, I_{NC} = 100 \text{ mA}$	Room		0.21	0.4	
			Full			0.55	Ω
r <sub>ON</sub> Match <sup>d</sup>	Δr <sub>ON</sub>	$V+ = 4.3 \text{ V}, V_{COM} = 0.9 \text{ to } 2.5 \text{ V+},$ $I_{NO}, I_{NC} = 100 \text{ mA}$	Room		0.03	0.06	
Switch Off Leakage	I <sub>NO(off)</sub> , I <sub>NC(off)</sub>	$V+ = 4.3 \text{ V}, V_{NO}, V_{NC} = 0.3 \text{ V} / 4.0 \text{ V},$ $V_{COM} = 4.0 \text{ V} / 0.3 \text{ V}$	Full	-20		20	
Current	I <sub>COM(off)</sub>		Full	-20		20	nA
Channel-On Leakage Current <sup>d</sup>	I <sub>COM(on)</sub>	$V+ = 4.3 \text{ V}, V_{NO}, V_{NC} = V_{COM} = 3.0 \text{ V} / 4.0 \text{ V}$	Full	-20		20	
Digital Control	-					•	
Input High Voltage	V <sub>IN</sub>		Full	1.6			V
Input Low Voltage	V <sub>INL</sub>		Full			0.5	v
Input Capacitance	C <sub>in</sub>		Full		-4		pF
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>IN</sub> = 0 or V+	Full	-1		1	μΑ
<b>Dynamic Characteristics</b>	•				I.		I.
Break-Before-Make Time	t <sub>BBM</sub>	$V_{NO}$ or $V_{NC}$ = 1.5 V, $R_L$ = 50 $\Omega$ , $C_L$ = 35 pF	Full	5			ns
Power Supply	•					•	
Power Supply Range	V+					4.3	V
Power Supply Current	I+	$V_{IN} = 0$ or $V+$	Full			1.0	μΑ

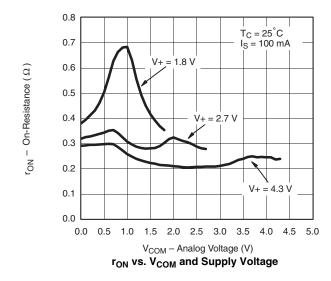
#### Notes

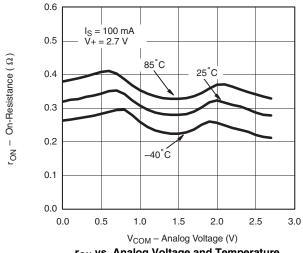
- a. Room = 25°C, Full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e.  $V_{IN}$  = input voltage to perform proper function.

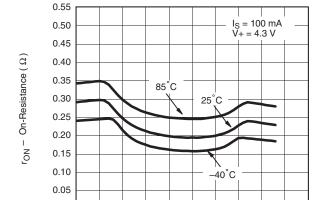
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



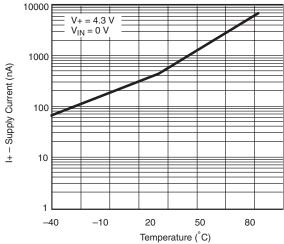
#### **TYPICAL CHARACTERISTICS** $T_A = 25 \, ^{\circ}\text{C}$ , unless otherwise noted







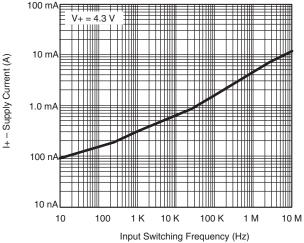




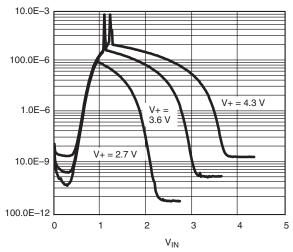
V<sub>COM</sub> – Analog Voltage (V) r<sub>ON</sub> vs. Analog Voltage and Temperature

2.0 2.5 3.0 3.5

4.0 4.5 5.0



Supply Current vs. Temperature



**Supply Current vs. Input Switching Frequency** 

Supply Current vs. V<sub>IN</sub>

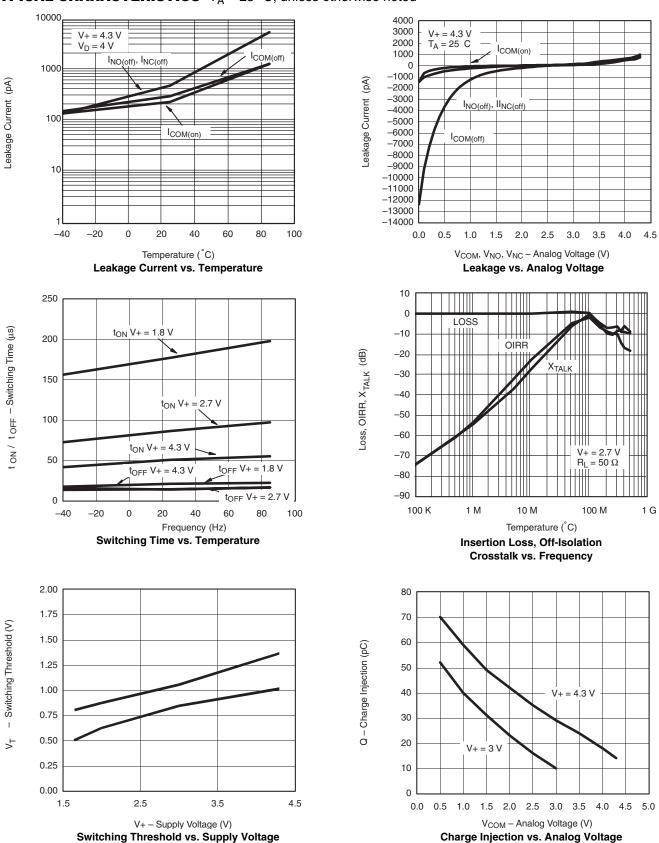
0.00

0.0 0.5

1.0 1.5

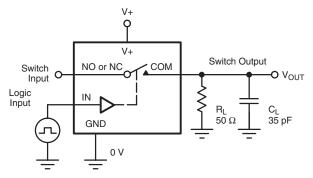
# VISHAY.

#### **TYPICAL CHARACTERISTICS** $T_A = 25$ °C, unless otherwise noted





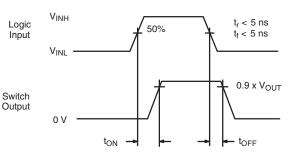
#### **TEST CIRCUITS**



C<sub>L</sub> (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM} \left( \frac{R_L}{R_L + R_{ON}} \right)$$

C<sub>L</sub> (includes fixture and stray capacitance)



Logic "1" = Switch On Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time

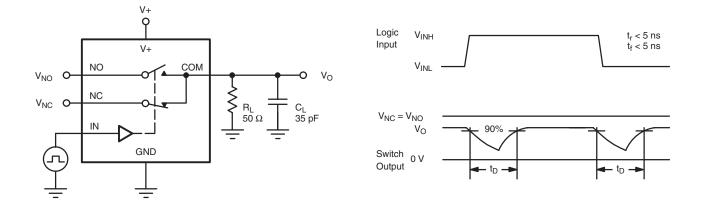


Figure 2. Break-Before-Make Interval

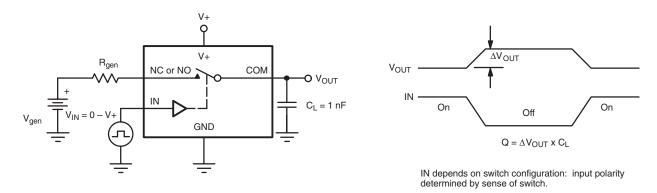


Figure 3. Charge Injection

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#### **TEST CIRCUITS**

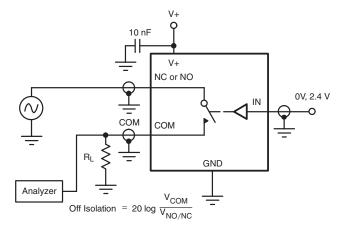


Figure 4. Off-Isolation

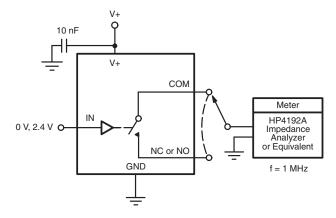


Figure 5. Channel Off/On Capacitance

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Document Number: 91000 Revision: 18-Jul-08

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